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National Semiconductor

54ACTQ543 Quiet Series Octal Registered Transceiver with TRI-STATE[®] Outputs

General Description

The ACTQ543 is a non-inverting octal transceiver containing two sets of D-type registers for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The ACTQ utilizes NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series[™] features GTO[™] output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

- Guaranteed simultaneous switching noise level and dynamic threshold performance
- 8-bit octal latched transceiver
- Separate controls for data flow in each direction
- Back-to-back registers for storage
- Outputs source/sink 24 mA
- 4 kV minimum ESD immunity

Ordering Code

Military	Package Number	Package Description
54ACTQ543DMQB	J24A	24-Lead Ceramic Dual-In-Line
54ACTQ543FMQB	W24C	24-Lead Cerpack
54ACTQ543LMQB	E28A	24-Lead Ceramic Leadless
		Chip Carrier, Type C



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Pin Names	Description
OEAB	A-to-B Output Enable Input (Active LOW)
OEBA	B-to-A Output Enable Input (Active LOW)
CEAB	A-to-B Enable Input (Active LOW)
CEBA	B-to-A Enable Input (Active LOW)
LEAB	A-to-B Latch Enable Input (Active LOW)
LEBA	B-to-A Latch Enable Input (Active LOW)
A ₀ -A ₇	A-to-B Data Inputs or
	B-to-A TRI-STATE Outputs
B ₀ -B ₇	B-to-A Data Inputs or
	A-to-B TRI-STATE Outputs

Functional Description

The ACTQ543 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable (CEAB) input must be LOW in order to enter data from A_0-A_7 or take data from B_0-B_7 , as indicated in the Data I/O Control Table. With CEAB LOW, a LOW signal on the A-to-B Latch Enable ((LEAB) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the LEAB signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With CEAB and OEAB both LOW, the TRI-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the CEBA, LEBA and OEBA inputs.

Data I/O Control Table

Inputs			Latch Status	Output Buffers
CEAB	LEAB	OEAB		
Н	Х	Х	Latched	High Z
X	Н	Х	Latched	—
L	L	Х	Transparent	—
X	Х	н	—	High Z
L	Х	L	—	Driving

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial

A-to-B data flow shown; B-to-A flow control is the same, except using CEBA, LEBA and OEBA



Absolute Maximum Ratings (Note 1)

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If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Input Diode Current (IIK)	
$V_{I} = -0.5V$	–20 mA
$V_{I} = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V _I)	–0.5V to V _{CC} + 0.5V
DC Output Diode Current (I _{OK})	
$V_{O} = -0.5V$	–20 mA
$V_{O} = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V _O)	–0.5V to V _{CC} + 0.5V
DC Output Source	
or Sink Current (I _O)	±50 mA
DC V _{CC} or Ground Current	
per Output Pin (I _{CC} or I _{GND})	±50 mA
Storage Temperature (T _{STG})	–65°C to +150°C

DC Latch-up Source or Sink Current Junction Temperature (T _J) CDIP	±300 mA 175°C
Recommended Operating Conditions	
Supply Voltage V _{CC} 'ACTQ	4.5V to 5.5V
Input Voltage (V _I)	0V to $V_{\rm CC}$
Output Voltage (V _O)	0V to V _{CC}

to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT® circuits outside databook specifications. Note 2: All commercial packaging is not recommended for applications requiring greater than 2000 temperature cycles from -40°C to +125°C.

DC Characteristics for 'ACTQ Family Devices

			54ACTQ		
Symbol	Parameter	V _{cc}	T _A =	Units	Conditions
		(V)	-55°C to +125°C		
			Guaranteed Limits		
VIH	Minimum High Level	4.5	2.0	V	V _{OUT} = 0.1V
	Input Voltage	5.5	2.0		or $V_{CC} - 0.1V$
V _{IL}	Maximum Low Level	4.5	0.8	V	V _{OUT} = 0.1V
	Input Voltage	5.5	0.8		or $V_{CC} - 0.1V$
V _{OH}	Minimum High Level	4.5	4.4	V	I _{OUT} = -50 μA
	Output Voltage	5.5	5.4		
					(Note 3)
					$V_{IN} = V_{IL} \text{ or } V_{IH}$
		4.5	3.70	V	I _{OH} = -24 mA
		5.5	4.70		I _{OH} = -24 mA
V _{OL}	Maximum Low Level	4.5	0.1	V	Ι _{ΟUT} = 50 μΑ
	Output Voltage	5.5	0.1		
					(Note 3)
					$V_{IN} = V_{IL} \text{ or } V_{IH}$
		4.5	0.50	V	I _{OL} = 24 mA
		5.5	0.50		I _{OL} = 24 mA
I _{IN}	Maximum Input	5.5	±1.0	μA	$V_{I} = V_{CC}, GND$
	Leakage Current				
I _{OZT}	Maximum I/O	5.5	±10	μA	$V_{(OE)} = V_{IL}, V_{IH}$
	Leakage Current				$V_{O} = V_{CC}, GND$
I _{CCT}	Maximum I _{CC} /Input	5.5	1.6	mA	$V_{I} = V_{CC} - 2.1V$
I _{OLD}	Minimum Dynamic	5.5		mA	V _{OLD} = 1.65V Max
	Output Current	5.5	-50	mA	Voup = 3.85V Min
-UHD	(Note 4)	0.0			
Icc	Maximum Quiescent	5.5	160.0	μΑ	$V_{IN} = V_{CC}$
	Supply Current				or GND (Note 5)

DC Characteristics for 'ACTQ Family Devices (Continued)							
			54ACTQ				
Symbol	Parameter	V _{cc}	T _A =	Units	Conditions		
		(V)	–55°C to +125°C				
			Guaranteed Limits				
V _{OLP}	Quiet Output	5.0	1.5	V	(Notes 6, 7)		
	Maximum Dynamic V _{OL}						
V _{OLV}	Quiet Output	5.0	-1.2	V	(Notes 6, 7)		
	Minimum Dynamic V _{OL}						

Note 3: Maximum of 8 outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: I_{CC} for 54ACTQ @ 25 $^\circ\text{C}$ is identical to 74ACTQ@ 25 $^\circ\text{C}.$

Note 6: Plastic DIP package.

Note 7: Max number of outputs defined as (n). (n–1) Data Inputs are driven 0V to 3V, one output @ GND.

Note 8: Max number of Data Inputs (n) switching. (n-1) Inputs switching 0V to 3V ('ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

			544	54ACTQ			
	_	Vcc	T _A = -55°C			Fig.	
Symbol	Parameter	Ň	to +	125°C	Units	No.	
		(Note 9)	C _L = 50 pF			-	
		(Min	Max			
t _{PLH}	Propagation Delay						
t _{PHL}	Transparent Mode	5.0	2.0	9.5	ns	Figure 4	
	A _n to B _n or B _n to A _n						
t _{PLH}	Propagation Delay					Figure 4	
t _{PHL}	LEBA, LEAB	5.0	2.0	11.0	ns		
	to A _n , B _n						
t _{PZH}	Output Enable Time					Figure 6	
t _{PZL}	$\overline{\text{OEBA}}$ or $\overline{\text{OEAB}}$ to A_n or B_n	5.0	1.5	13.0	ns		
	$\overline{\text{CEBA}}$ or $\overline{\text{CEAB}}$ to A_n or B_n						
t _{PHZ}	Output Disable Time					Figure 6	
t _{PLZ}	$\overline{\text{OEBA}}$ or $\overline{\text{OEAB}}$ to A_n or B_n	5.0	1.5	9.0	ns		
	$\overline{\text{CEBA}}$ or $\overline{\text{CEAB}}$ to A_n or B_n						

Note 9: Voltage Range 5.0 is 5.0V $\pm 0.5V$

AC Operating Requirements

			54ACTQ		
			T _A = -55°C		
Symbol	Parameter	V _{cc}	to +125°C	Units	Fig.
		(V)	С _L = 50 pF		No.
		(Note 10)	Guaranteed		
			Minimum		
t _s	Setup Time, HIGH or LOW	5.0	3.0	ns	Figure 7
	A_n or B_n to LEBA or LEAB				
t _h	Hold Time, HIGH or LOW	5.0	1.5	ns	Figure 7
	A_n or B_n to LEBA or LEAB				
t _w	Latch Enable	5.0	4.0	ns	Figure 5
	Pulse Width, LOW				
Note 10: Voltag	e Range 5.0 is 5.0V ±0.5V				

Capacitance

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Symbol	Parameter	Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	$V_{CC} = OPEN$
C _{PD}	Power Dissipation	70.0	pF	$V_{CC} = 5.0V$
	Capacitance			

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load



FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t _w	t,	t _f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms



FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions







FIGURE 6. TRI-STATE Output High and Low Enable and Disable Time









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